

**DESCRIPTION:**

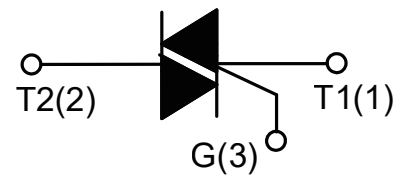
With high ability to withstand the shock loading of large current, BTA216B-600D series triacs provide high dv/dt rate with strong resistance to electro-magnetic interface. With high commutation performances, 3 quadrants products especially recommended for use on inductive load.



TO-263

**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	600/800/1200	V


**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-125	°C
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	600/800/1200	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	600/800/1200	V
Non repetitive surge peak Off-state voltage	$V_{DSM}$	$V_{DRM} + 100$	V
Non repetitive peak reverse voltage	$V_{RSM}$	$V_{RRM} + 100$	V
RMS on-state current	$I_{T(RMS)}$	16	A
TO-263 ( $T_C=80^\circ\text{C}$ )			
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$ )	$I_{TSM}$	160	A
$I^2t$ value for fusing ( $t_p=10\text{ms}$ )	$I^2t$	128	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ )	$di/dt$	50	$\text{A}/\mu\text{s}$
Peak gate current	$I_{GM}$	4	A
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	5	W

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^\circ\text{C}$  unless otherwise specified)

**3 Quadrants**

Symbol	Test Condition	Quadrant		Value				Unit
				BW	CW	SW	TW	
$I_{GT}$	$V_D=12\text{V } R_L=33\Omega$	I - II -III	MAX	50	35	10	5	mA
$V_{GT}$		I - II -III	MAX	1.3				V
$V_{GD}$	$V_D=V_{DRM} T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	I - II -III	MIN	0.2				V
$I_L$	$I_G=1.2I_{GT}$	I -III	MAX	70	50	30	15	mA
		II		80	60	40	20	
$I_H$	$I_T=100\text{mA}$		MAX	60	40	25	15	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$		MIN	1000	500	200	100	V/ $\mu\text{s}$

**4 Quadrants**

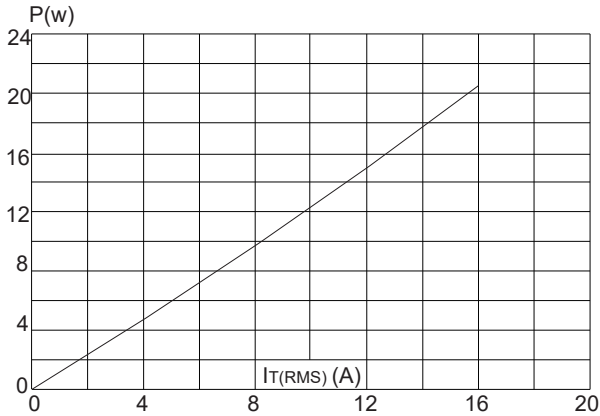
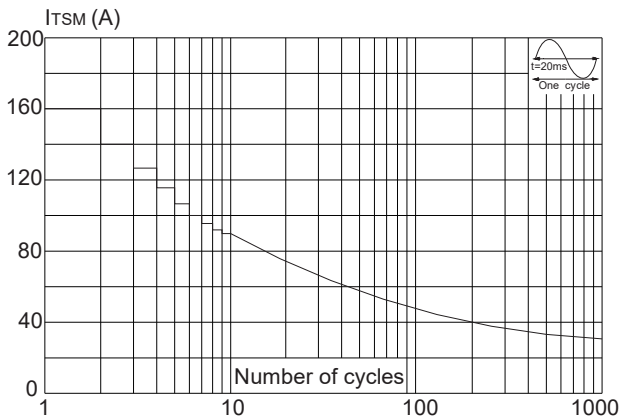
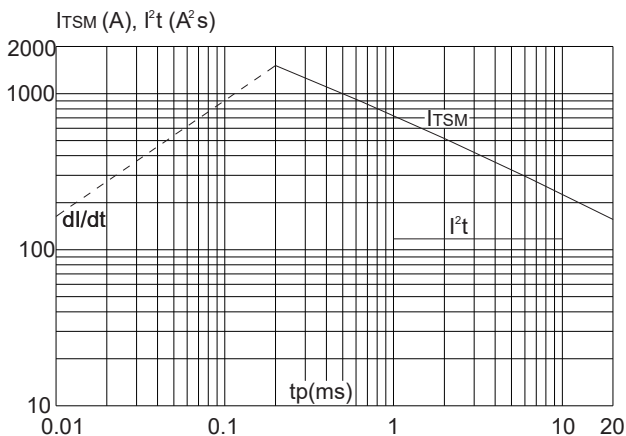
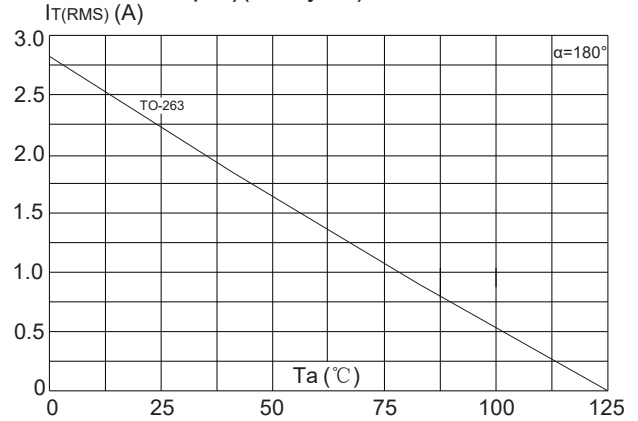
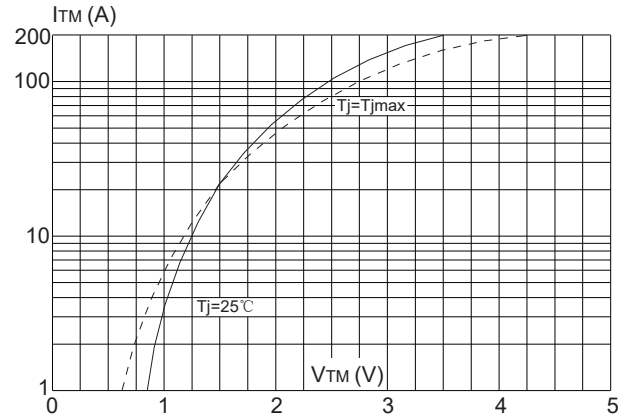
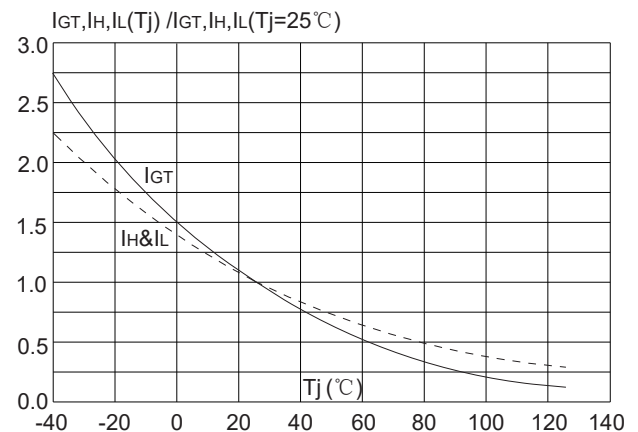
Symbol	Test Condition	Quadrant		Value		Unit
				B	C	
$I_{GT}$	$V_D=12\text{V } R_L=33\Omega$	I - II -III	MAX	50	25	mA
		IV		70	50	
$V_{GT}$		ALL	MAX	1.5		V
$V_{GD}$	$V_D=V_{DRM} T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	ALL	MIN	0.2		V
$I_L$	$I_G=1.2I_{GT}$	I -III-IV	MAX	70	50	mA
		II		100	80	
$I_H$	$I_T=100\text{mA}$		MAX	60	40	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$		MIN	500	200	V/ $\mu\text{s}$

**STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX)			Unit
			-600V	-800V	-1200V	
$V_{TM}$	$I_{TM}=22.5\text{A } t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.5			V
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	5	5	10	$\mu\text{A}$
$I_{RRM}$		$T_j=125^\circ\text{C}$	1	1	2	mA

**THERMAL RESISTANCES**

<b>Symbol</b>	<b>Parameter</b>		<b>Value</b>	<b>Unit</b>
$R_{th(j-c)}$	junction to case(AC)	TO-263	2.5	°C/W
$R_{th(j-a)}$	junction to ambient		45	

**FIG.1** Maximum power dissipation versus RMS on-state current

**FIG.3:** Surge peak on-state current versus number of cycles

**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $di/dt < 50\text{A}/\mu\text{s}$ )

**FIG.2:** RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness:  $35\mu\text{m}$ ) (full cycle)

**FIG.4:** On-state characteristics (maximum values)

**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature


**SOLDERING PARAMETERS**

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150°C
	-Temperature Max( $T_{s(max)}$ )	+200°C
	-Time (Min to Max) ( $t_s$ )	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3°C/sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature( $T_L$ ) (Liquidus)	+217°C
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)°C
Time within 5°C of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp ( $T_p$ )		8 min. Max
Do not exceed		+260°C

